Experimental evidence of the topological obstruction in twisted graphene layers

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Twisted graphene layers have attracted much interest owing to the rich and correlated tuneable strongly electron physics that they host¹. An important aspect of their physics is the topology of the electronic bands which determines how the strongly correlated electron physics expresses. However, accessing this topology experimentally is difficult. Here we use the local density of states (LDOS) probed by scanning tunnelling microscopy as a topological observable² to explore the relative chirality of the Dirac cones within a moiré valley. We discover a chiral pattern (Fig. 1) near a charged defect which results from the Dirac cones having the same chirality within a moiré valley. This is expected from the continuum low-energy model of twisted graphene layers³ and has consequences important for the emergence of Chern insulating and orbital magnet states⁴. Also, this peculiar topology leads to a topological obstruction of the low energy description of twisted graphene which confirmed layers⁵ is now experimentally.

References

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Figures

0 0.2 0.4 0.6 0.8 1 arb. units





Figure 1: a) Tunnelling conductance map showing the LDOS measured near a charged defect in twisted graphene layers (V_b = 200 mV, i_t = 100 pA). b) STM topography image showing the defect and the moiré pattern. The dotted square in (a) shows the area. c) Low frequency FFT of the image in (a).

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